TOSHIBA Photocoupler IRED+Photo-IC

# **TLP759**

Digital Logic Ground Isolation Line Receiver Microprocessor System Interfaces Switching Power Supply Feedback Control Industrial Inverter

The TOSHIBA TLP759 consists of a high-output infrared emitting diode and a high speed detector of one chip photo diode-transistor. This unit is 8-lead DIP.

TLP759 has no internal base connection, and a Faraday shield integrated on the photodetector chip provides an effective common mode noise transient immunity.

So this is suitable for application in noisy environmental condition.

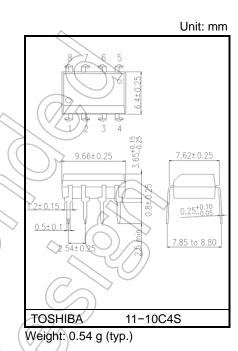
- Isolation voltage: 5000 Vrms (min)
- Switching speed:  $t_{pHL} = 0.2 \mu s$  (typ.)

 $t_{pLH} = 0.3 \mu s (typ.) (R_L = 1.9 \text{ k}\Omega)$ 

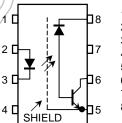
- TTL compatible
- UL-recognized: UL 1577, File No. E67349
- cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349
- VDE-approved: EN 60747-5-5 (Note 1)

Note 1: When a VDE approved type is needed, please designate the **Option (D4)**.

 Mechanical Parameters Creepage distance: 7.0 mm (min) Clearance: 7.0 mm (min) Insulation thickness: 0.4 mm (min)

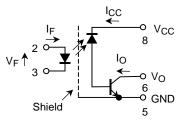


#### Pin Configuration (top view)



- 1: N.C. 2: Anode
- 3: Cathode
- 4: N.C.
- 5: Emitter(gnd)
- 6: Collector(output)
- 7: N.C. 8: Vcc

#### Schematic



Start of commercial production 1993-01

Absolute Maximum Ratings (Ta = 25°C)

|                                | Characteristic                               |                 | Symbol           | Rating     | Unit    |
|--------------------------------|--|-----------------|------------------|------------|---------|
| LED                            | Forward current                              |                 | ١ <sub>F</sub>   | 25         | mA      |
|                                | Forward current derating (Ta ≥70°C)          |                 | IF / Ta          | -0.8       | mA / °C |
|                                | Pulse forward current                        | (Note 1)        | IFP              | 50         | mA      |
|                                | Peak transient forward current               | (Note 2)        | IFPT             |            | А       |
|                                | Reverse voltage                              |                 | VR               | 5          | V       |
|                                | Diode power dissipation                      | (Note 3)        | PD               | 45         | mW      |
|                                | Output current                               |                 | 9                | 8          | mA      |
|                                | Peak output current                          |                 | IOP              | 16         | mA      |
| Detector                       | Output voltage                               |                 | Vo               | -0.5 to 20 | V       |
|                                | Supply voltage                               | ~               | Vcc              | -0.5 to 30 | V       |
|                                | Output power dissipation                     |                 | Ро               | 100        | mW      |
|                                | Output power dissipation derating (Ta ≥70°C) | $(\mathcal{O})$ | Po/Ta            | -2         | m₩/°C   |
| Ope                            | Operating temperature range                  |                 |                  | -55 to 100 | Э°С     |
| Stor                           | rage temperature range                       |                 | T <sub>stg</sub> | -55 to 125 | ℃       |
| Lead solder temperature (10 s) |  | (Note 4)        | T <sub>sol</sub> | 260        | °C      |
| Isola                          | ation voltage (AC, 60 s, R.H. ≤ 60 %)        | (Note 5)        | BVs              | 5000       | Vrms    |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

(Note 1) 50 % duty cycle, 1 ms pulse width. Derate 1.6 mA / °C above 70 °C.

(Note 2) Pulse width  $\leq$  1 µs, 300 pps.

- (Note 3) Derate 0.9 mW / °C above 70 °C.
- (Note 4) Soldering portion of lead: Up to 2 mm from the body of the device.
- (Note 5) Device considered a two terminal device: Pins 1, 2, 3 and 4 shorted together and pins 5, 6, 7 and 8 shorted together.

**Electrical Characteristics (Ta = 25°C)** 

|          | Characteristic                          | Symbol                          | Test Condition  | Min                  | Тур. | Max  | Unit   |
|----------|---|---------------------------------|---|----------------------|------|------|--------|
|          | Forward voltage                         | VF                              | I <sub>F</sub> = 16 mA  | —                    | 1.65 | 1.85 | V      |
| LDE      | Forward voltage temperature coefficient | ΔVϝ/ΔΤα                         | IF = 16 mA  | _                    | -2   |      | mV /°C |
|          | Reverse current                         | I <sub>R</sub>                  | V <sub>R</sub> = 5 V  | $\overline{\langle}$ | -    | 10   | μA     |
|          | Capacitance between terminals           | Ст                              | V = 0 V, f = 1 MHz  | $\langle - \rangle$  | 45   | _    | pF     |
|          | High level output current               | IOH (1)                         | IF = 0 mA, VCC = VO = 5.5 V   |                      | 3    | 500  | nA     |
| or       |   | IOH (2)                         | IF = 0 mA, V <sub>CC</sub> = 30 V, V <sub>O</sub> = 20 V                      |                      | _    | 5    |        |
| Detector |   | Юн                              | $I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}, V_O = 20 \text{ V}$<br>Ta = 70 °C | 9_                   | _    | 50   | μΑ     |
|          | High level supply voltage               | Іссн                            | IF = 0 mA, VCC = 30 V   | _                    | 0.01 | 1    | μΑ     |
|          | Current transfer ratio                  | I <sub>O</sub> / I <sub>F</sub> | IF = 16 mA, VCC = 4.5 V<br>Vo = 0.4 V   | 20                   | 40   |      | %      |
| Coupled  | Low level output voltage                | Vol                             | IF = 16 mA, VCC = 4.5 V<br>IO = 2.4 mA  | -2                   | X    | 0.4  | V      |
|          | Resistance (input-output)               | Rs                              | R.H.≤ 60 %, V <sub>S</sub> = 500 V (Note 5)                                   | 1×10 <sup>12</sup>   | 1014 | _    | Ω      |
|          | Capacitance (input-output)              | Cs                              | Vs = 0 V, f = 1 MHz (Note 5)  | $\mathcal{A}_{\ell}$ | 0.8  |      | pF     |
|          | Isolation voltage                       | BVs                             | AC, 60 s (Note 5)   | 5000                 | _    | _    | Vrms   |

### Switching Characteristics (Ta = $25^{\circ}$ C, VCC = 5V)

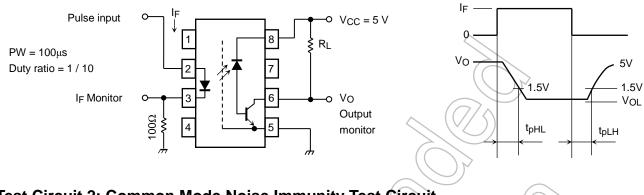
| Characteristic  | Symbol | Test<br>Circuit | Test Condition   | Min   | Тур.   | Max | Unit   |
|---|--------|-----------------|--|-------|--------|-----|--------|
| Propagation delay time $(H \rightarrow L)$                      | tpHL   | 1               | $IF = 0 \rightarrow 16 \text{ mA}, \\ R_L = 1.9 \text{ k}\Omega$                   | _     | 0.2    | 0.8 | μS     |
| Propagation delay time $(L \rightarrow H)$                      | (tpLH  |                 | $I_F = 16 \rightarrow 0 \text{ mA},$<br>RL = 1.9 kΩ                                | _     | 0.3    | 0.8 | μS     |
| Common mode transient immunity<br>at logic high output (Note 1) | CMH    | 2               | $I_{F} = 0 \text{ mA}, V_{CM} = 400 \text{ V}_{p-p}$ $R_{L} = 4.1 \text{ k}\Omega$ | 5000  | 10000  | _   | V / μs |
| Common mode transient immunity<br>at logic low output (Note 1)  | CML    |                 | $IF = 16 \text{ mA}, V_{CM} = 400 V_{p-p}$<br>RL = 4.1 kΩ                          | -5000 | -10000 | _   | V / μs |

(Note 1) CM<sub>L</sub> is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state (VO < 0.8 V).

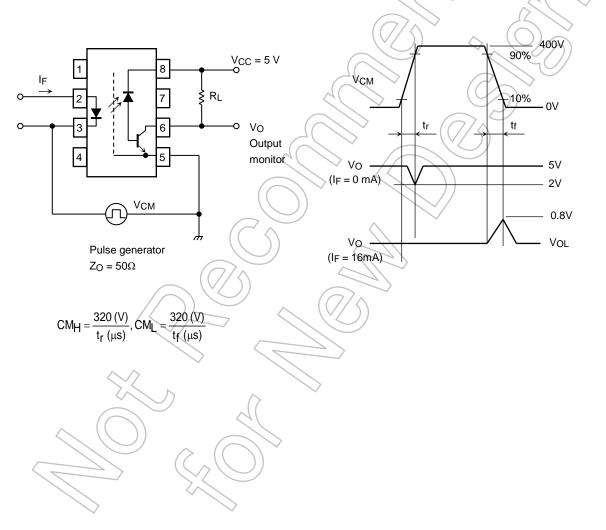
CM<sub>H</sub> is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ( $V_O > 2.0 V$ ).

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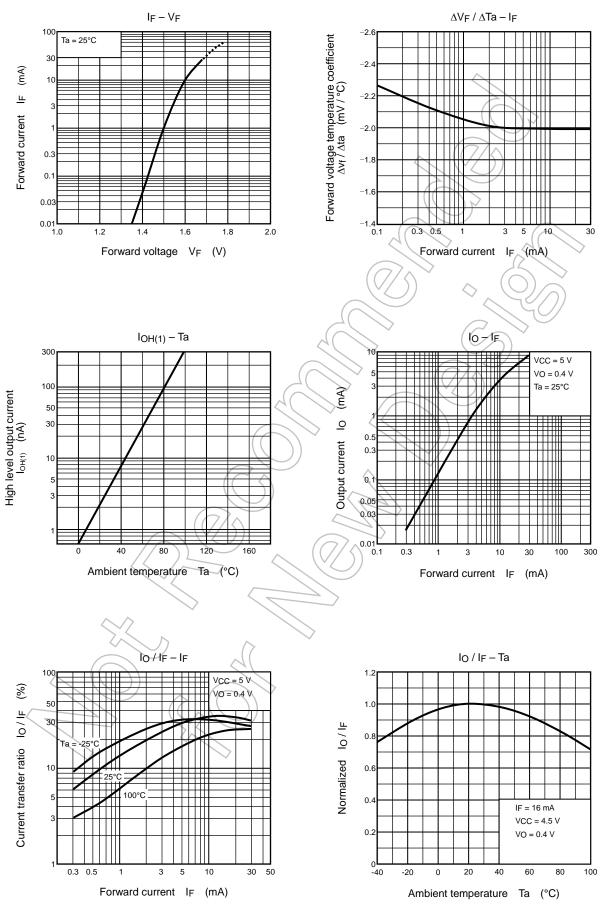
#### Test Circuit 1: Switching Time Test Circuit

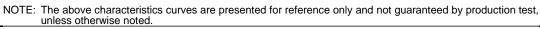




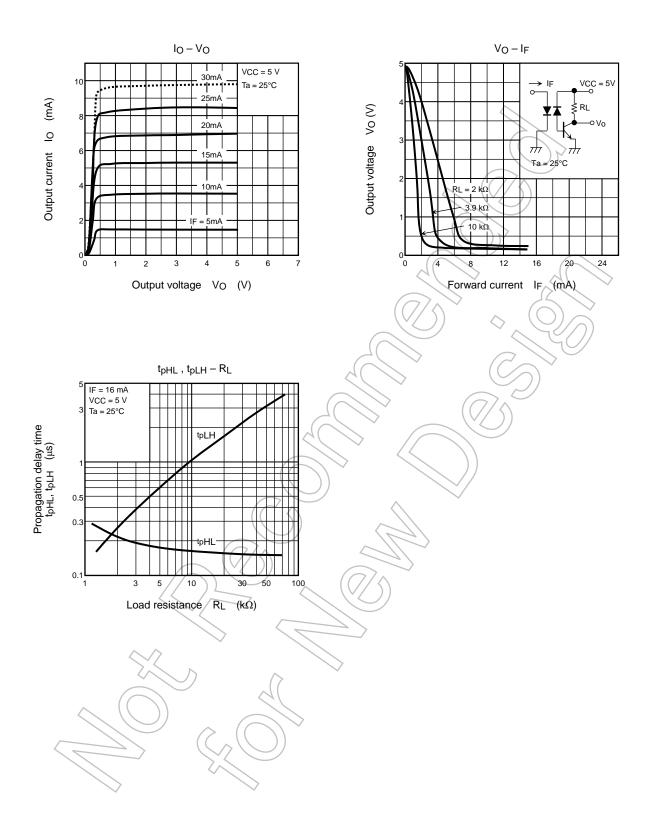


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NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

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